



Linear Constant Current Regulated LED Driver

DESCRIPTION

The TSCR420 & TSCR421 are Low-Side Constant Current Regulator (CCR) for linear LED driving. The device regulates with a preset 10mA nominal that can be adjusted with an external resistor up to 300mA. It is designed for driving LEDs in strings and will reduce current at increasing temperatures to self-protect. Operating as a series linear CCR for LED string current control, it can be used in multiple applications, as long as the maximum supply voltage to the device is <40V.

With the low-side control, the TSCR421 has an Enable (EN) pin which can be pulse-width modulated (PWM) up to 10kHz by a microcontroller for LED dimming.

The output current at higher temperatures is the result of the negative temperature coefficient of 0.07%/°C of the LED driver.

FEATURES

-

- AEC-Q100 qualified with the following results:
 - Device temperature grade 1: -40°C to 125°C
 - Device HBM ESD classification level H2
 - Device CDM ESD classification level C6
- LED drive current preset to 10mA
- Continuous output current up to 300mA with an external resistor
- Very low enable current
- · Easy paralleling of drivers to increase current
- Supply voltage up to 40V
- Digital PWM input up to 10kHz (TSCR421)
- Good temperature coefficient vs. output current
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC.
- Halogen-Free according to IEC 61249-2-21

APPLICATION

- Automotive Lighting
- Architectural LED lighting, emergency lighting
- Signage, Advertising, Decorative Lighting
- Retail Lighting in Fridges and Vending Machines



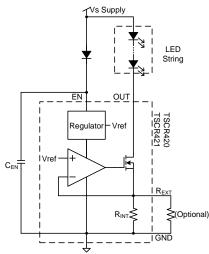


in Definition:				
1. EN	6. R _{EXT}			
2. OUT	5. OUT			
3. OUT	4. GND			

P

Notes: MSL 1 (Moisture Sensitivity Level) per J-STD-020

TYPICAL APPLICATION CIRCUIT





ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified) (Note 1)				
PARAMETER		SYMBOL	LIMIT	UNIT
Enable voltage	TSCR420	N/	40	V
	TSCR421	V _{EN}	4.5	V
Output current		I _{OUT}	300	mA
Output voltage		V _{OUT}	40	V
Reverse voltage between all terminals		V _R	0.5	V
Total power dissipation @ T _A =25 °C ^(Note)		P _{TOT}	1	W
Junction temperature range		TJ	-55 to +150	°C
Operating ambient temperature range		T _A	-40 to +125	°C
Storage temperature range		T _{STG}	-65 to +150	°C
ESD Rating (Human Body Model)		HBM	±2	kV
ESD Rating (Charge Device Model)		CDM	±1	kV

Note:

Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit.

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Thermal Resistance - Junction to Ambient	R _{ØJA}	225	°C/W	
Thermal Resistance - Junction to Case	R _{eJC}	125	°C/W	
Thermal Resistance - Junction to Lead	R _{eJL}	145	°C/W	

ELECTRICAL SPECIFICATIONS ($T_A = 25^{\circ}C$ unless otherwise noted)							
PARAMETER		CONDITIONS	SYMBOL	MIN	ТҮР	MAX	UNIT
Break Down Voltage			V _{BR}	40			V
Enable Current	TSCR420	V _{EN} =24V			450		μA
	TSCR421	V _{EN} =3.3V	I _{EN}		36		μA
Internal Resistor		I _{RINT} =10mA	R _{INT}	85	95	105	Ω
Output Current	TSCR420	V_{OUT} =1.4V, V_{EN} =24V	- I _{оит}	9	10	11	mA
Output Current	TSCR421	V_{OUT} =1.4V, V_{EN} =3.3V		9	10	11	
Output Current at	TSCR420	V _{OUT} >2.0V, V _{EN} =24V			150		
$R_{EXT}=5.1\Omega$	TSCR421	V _{OUT} >2.0V, V _{EN} =3.3V			150		
Voltage Drop (V _{REXT})		I _{OUT} =10mA	V _{DROP}	0.85	0.95	1.05	V
Minimum Output Voltage	Э	I _{OUT} >18mA	V _{OUT(MIN)}		1.4		V
Output Current vs. Temperature	TSCR420	V _{OUT} >2.0V, V _{EN} =24V	ΔI _{OUT} /I _{OUT}		-0.07		%/°C
	TSCR421	V _{OUT} >2.0V, V _{EN} =3.3V			-0.07		
Output Current vs. Supply Voltage	TSCR420	V _{OUT} >2.0V, V _{EN} =24V	AL //		0.33		0())
	TSCR421	V _{OUT} >2.0V, V _{EN} =3.3V	Δl _{out} /l _{out}		0.33		%/V

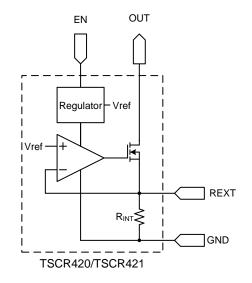


Taiwan Semiconductor

ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TSCR420CX6H RFG	SOT-26	3,000pcs / 7"Reel
TSCR421CX6H RFG	SOT-26	3,000pcs / 7"Reel

FUNCTION BLOCK

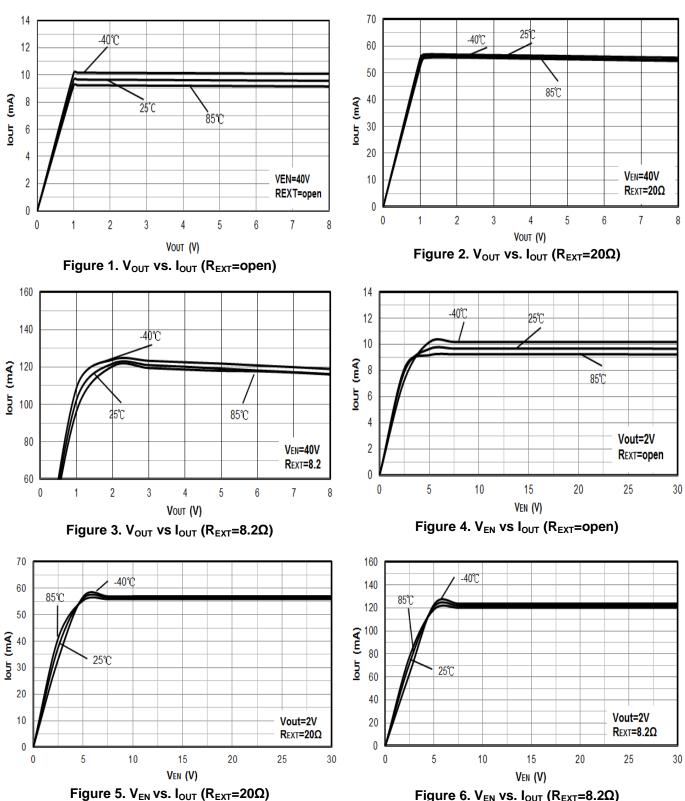


PIN DESCRIPTION

PIN NO.	NAME	FUNCTION
1	EN	Enable for biasing transistor
2	OUT	Regulated output current
3	OUT	Regulated output current
4	GND	Power ground
5	OUT	Regulated output current
6	R _{EXT}	External resistor for adjusting output current



Taiwan Semiconductor

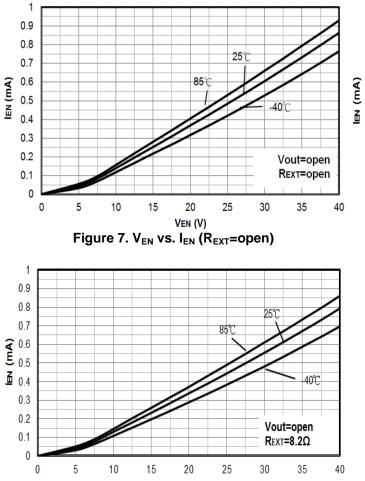


TSCR420CX6 CHARACTERISTICS CURVES

Figure 6. V_{EN} vs. I_{OUT} (R_{EXT}=8.2Ω)



Taiwan Semiconductor



TSCR420CX6 CHARACTERISTICS CURVES

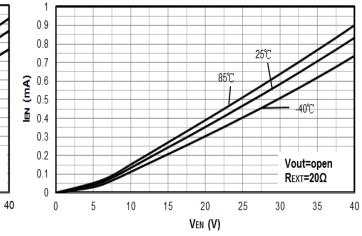
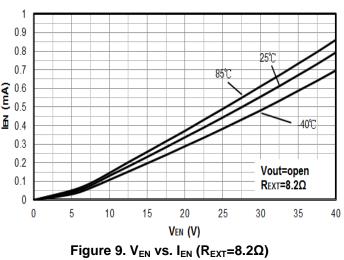
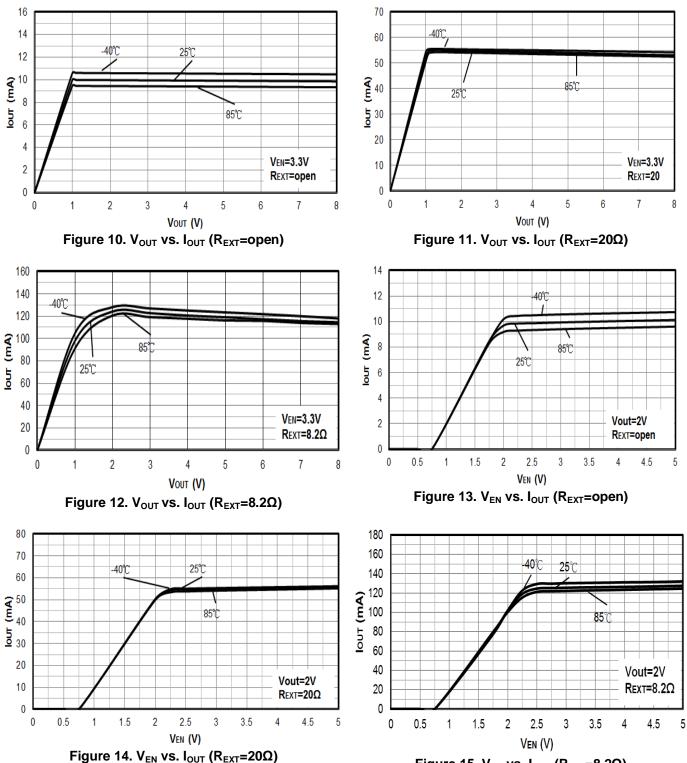


Figure 8. V_{EN} vs. I_{EN} (R_{EXT}=20Ω)





Taiwan Semiconductor

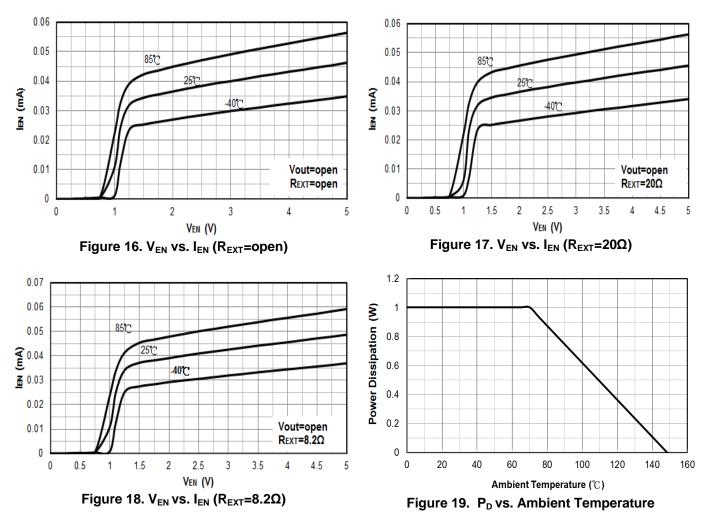


TSCR421CX6 CHARACTERISTICS CURVES

Figure 15. V_{EN} vs. I_{OUT} (R_{EXT}=8.2Ω)



Taiwan Semiconductor



TSCR421CX6 CHARACTERISTICS CURVES



APPLICATION INFORMATION

The TSCR420 & TSCR421 are designed for driving low current LEDs with typical LED currents of 10mA to 300mA. They provide a cost-effective way for driving low current LEDs compared with more complex switching regulator solutions. Furthermore, they reduce the PCB board area of the solution as there is no need for external components like inductors, capacitors and switching diodes

Figure 20 shows a typical application circuit diagram for driving an LED or string of LEDs. The device comes with an internal resistor (R_{INT}) of typically 95 Ω , which in the absence of an external resistor, sets an LED current of 10mA (typical) from a V_{EN} = 3.3V and V_{OUT} = 1.4V for TSCR421; or V_{EN} = 24V and V_{OUT} = 1.4V for TSCR420. LED current can be increased to a desired value by choosing an appropriate external resistor, R_{EXT} .

The R_{EXT} vs I_{OUT} graphs should be used to select the appropriate resistor. Choosing a low tolerance R_{EXT} will improve the overall accuracy of the current sense formed by the parallel connection of R_{INT} and R_{EXT} .

 $R_{EXT} = V_{DROP} / (I_{OUT} - (V_{DROP}/R_{INT}))$

Two or more TSCR420 & TSCR421 can be connected in parallel to construct higher current LED strings as shown in Figure 21. Consideration of the expected linear mode power dissipation must be factored into the design, with respect to the TSCR420 & TSCR421's thermal resistance. The maximum voltage across the device can be calculated by taking the maximum supply voltage and subtracting the voltage across the LED string.

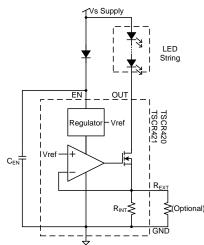
$$V_{OUT} = V_{S} - V_{LED}$$

$$P_{D} = (V_{OUT} - V_{REXT}) \times I_{LED} + (V_{EN} \times I_{EN})$$

As the output current of TSCR420 & TSCR421 increases, it is necessary to provide appropriate thermal relief to the device. The power dissipation supported by the device is dependent upon the PCB board material, the copper area and the ambient temperature. The maximum dissipation the device can handle is given by:

 $\mathsf{P}_{\mathsf{D}} = (\mathsf{T}_{\mathsf{J}(\mathsf{MAX})} - \mathsf{T}_{\mathsf{A}}) / \mathsf{R}_{\mathsf{\theta}\mathsf{J}\mathsf{A}}$

Refer to the thermal characteristic graphs on Page 4 for selecting the appropriate PCB copper area.





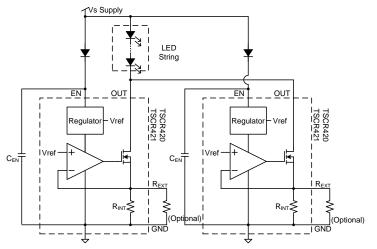


Figure 21: Application Circuit for Increasing LED Current



Taiwan Semiconductor

APPLICATION INFORMATION (CONTINUE)

PWM dimming can be achieved by driving the EN pin. Dimming is achieved by turning the LEDs ON and OFF for a portion of a single cycle. The PWM signal can be provided by a micro-controller or analog circuitry; typical circuit is shown in Figure 22.

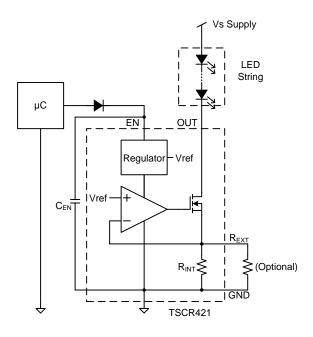


Figure 22: Application Circuit for LED Driver with PWM Dimming Functionality

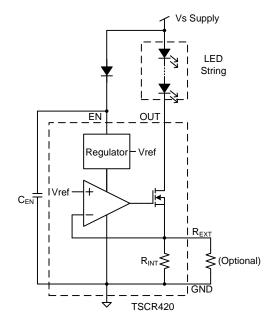


Figure 23: Application Circuit for LED Driver with High voltage EN Pin



0.413 +0.05 - 0.15

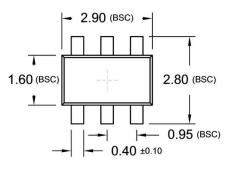
0.60 (REF)

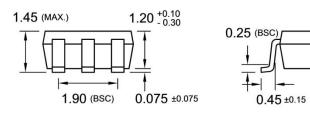
0.787 +0.05

Taiwan Semiconductor

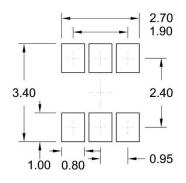
PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

SOT-26





SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Nx = Device Code

N1 =TSCR420CX6 N2 =TSCR421CX6

 $\mathbf{Y} = \text{Year Code}$

M = Month Code for Halogen Free Product

O=JanP=FebQ=MarR=AprS=MayT=JunU=JulV=AugW=SepX=OctY=NovZ=Dec

L = Lot Code $(1 \sim 9, A \sim Z)$